MSW2050-205 & MSW2051-205 **Series Datasheet**





LEAD FREE

Features

- Wide frequency range: 50 MHz to 4 GHz, in 2 bands
- Surface mount SP2T switch in compact outline: 8 mm L x 5 mm W x 2.5 mm H
- Higher average power handling than plastic packaged MMIC switches: 158 W CW
- High voltage rating for high RF peak power: 630 W
- Low insertion loss: 0.25 dB
- High IIP3: 65 dBm
- Operates with positive voltage (5 V, 28 V to 125 V)
- RoHS compliant

Applications

- High Power Transmit/Receive (TR) Switching
- **Active Receiver Protection**

Description

The MSW2050-205, MSW2051-205 series of surface mount silicon PIN diode SP2T switches handle high power signals from 50 MHz to 1 GHz, 400 MHz to 4 GHz respectively, in transmit-receive (TR), active receiver protection and other applications. This series is manufactured using Aeroflex/Metelics proven hybrid manufacturing process incorporating high voltage PIN diodes and passive devices integrated within a ceramic substrate. These low profile, compact, surface mount components, (8 mm Lx 5 mm Wx 2.5 mm H) offer superior small and large signal performance to that of MMIC devices in QFN packages. The SP2T switches are designed in an asymmetrical topology to minimize Tx-Ant loss and maximize Tx-Rx isolation performance. The very low thermal resistance (< 15°C/W) of the PIN diodes in these devices enables them to reliably handle RF incident power levels of 50 dBm CW and RF peak incident power levels of 58 dBm in cold switching applications at $T_A = 25$ °C. The low PIN diode series resistance (< 1.0 Ω), coupled with their long minority carrier lifetime, (> 1.5 μs), provides input third order intercept point (IIP3) greater than 65 dBm.

Applications

These MSW2050-205, MSW2051-205 SP2T switches are designed to be used in high average and peak power switch applications, operating from 50 MHz to 4 GHz in two bands, which utilize high volume, surface mount, solder re-flow manufacturing. These products are durable and capable of reliably operating in military, commercial, and industrial environments. The devices are RoHS compliant.



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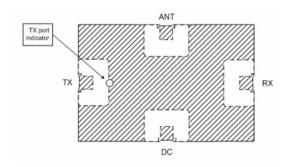
Environmental Capabilities

The MSW2050-205 and MSW2051-205 Series SP2T Switches are capable of meeting the environmental requirements of MIL-STD-202 and MIL-STD-750.

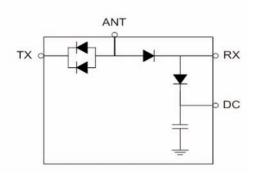
ESD and Moisture Sensitivity Level Rating

PIN Diode switches are susceptible to damage from ESD events, as are all semiconductors. The ESD rating for these devices is Class 1C, HBM. The moisture sensitivity level rating is MSL 1.

Pin Out



Schematic



Truth Table

Ant – Tx Path	Ant – Rx Path	Tx Bias	ANT Bias	Rx Bias	DC Bias
Low insertion loss	Isolation	-100 mA	100 mA	25 mA @ 28 V	-25 mA
Isolation	Low insertion loss	28 V	25 mA	-25 mA	28 V



MSW2050-205 Electrical Specifications

 $Z_0 = 50 \Omega$, $T_A = 25$ °C (Unless Otherwise Defined)

Parameter	Symbol	Test Conditions	Min. Value	Typ. Value	Max. Value	Units
Frequency	F		50		1000	MHz
Tx-Ant Insertion Loss	IL(Tx)	Condition 1		0.15	0.25	dB
Ant-Rx Insertion Loss	IL(Rx)	Condition 2		0.25	0.35	dB
Tx-Ant Return Loss	RL(Tx)	Condition 1	18	20		dB
Ant-Rx Return Loss	RL(Rx)	Condition 2	20	22		dB
Tx-Rx Isolation	Isol(Rx)	Condition 1	47	50		dB
Rx-Tx Isolation	Isol(Tx)	Condition 2	23	26		dB
TX CW Incident Power (Note 2)	P _{inc} (CW)	Condition 1, 1.5:1 source & load VSWR			52	dBm
RX CW Incident Power (Note 2)	P _{inc} (CW)	Condition 2, 1.5:1 source & load VSWR			43	dBm
TX Peak Incident Power (Note 2)	P _{inc} (Pk)	Condition 1, 10 µs pulse width, 1 % duty cycle, 1.5:1 source & load VSWR (IL)			58	dBm
Switching Time (Note 1)	t _{sw}	10% -90% RF Voltage		2	3	μs
Input 3rd Order Intercept Point	IIP3	$F_1 = 500 \text{ MHz}, F_2 = 501 \text{ MHz},$ $P_1 = P_2 = 40 \text{ dBm}$	60	65		dBm

MSW2051-205 Electrical Specifications

 $Z_0 = 50 \Omega$, $T_A = 25$ °C (Unless Otherwise Defined)

Parameter	Symbol	Test Conditions	Min. Value	Typ. Value	Max. Value	Units
Frequency	F		400		4000	MHz
Tx-Ant Insertion Loss	IL(Tx)	Condition 1		0.3	0.4	dB
Ant-Rx Insertion Loss	IL(Rx)	Condition 2		0.8	0.9	dB
Tx-Ant Return Loss	RL(Tx)	Condition 1	15	17		dB
Ant-Rx Return Loss	RL(Rx)	Condition 2	15	17		dB
Tx-Rx Isolation	Isol(Rx)	Condition 1	32	34		dB
Rx-Tx Isolation	Isol(Tx)	Condition 2	11	13		dB
TX CW Incident Power (Note 2)	P _{inc} (CW)	Condition 1, 1.5:1 source & load VSWR			52	dBm
RX CW Incident Power (Note 2)	P _{inc} (CW)	Condition 2, 1.5:1 source & load VSWR			43	dBm
TX Peak Incident Power (Note 2)	P _{inc} (Pk)	Condition 1, 10 µs pulse width, 1 % duty cycle, 1.5:1 source & load VSWR (IL)			58	dBm
Switching Time (Note 1)	t _{sw}	10% -90% RF Voltage		1.5	2	μs
Input 3rd Order Intercept Point	IIP3	F1 = 2.0 GHz, F2 = 2.01 GHz, P1 = P2 = 40 dBm	60	65		dBm

Notes:

- Switching Speed (50 % TTL 10/90 % RF Voltage) is a function of the PIN diode driver performance as well as the characteristics of the diode. An RC "current spiking network" is used on the driver output to provide a transient current to rapidly remove stored charge from the PIN diode. Typical component values are: R = 50 to 220 Ω and C = 470 to 1,000 pF. Aeroflex/Metelics MPD2T28125-700 is the recommended PIN diode driver to interface with the MSW2050-205, MSW2051-205 SP2T switches. Its data sheet may be found at (http://www.aeroflex.com/ams/metelics/micro-metelics-products.cfm).
- 2 PIN diode DC reverse voltage to maintain high resistance in the OFF PIN diode is determined by RF frequency, incident power, and VSWR as well as by the characteristics of the diode. The minimum reverse bias voltage values are provided in this datasheet. The input signal level applied for small signal testing is approximately 0 dBm.



RF Bias Network Component Values

P/N	F (MHz)	DC Blocking Capacitors	Inductors	RF Bypass Capacitors
MSW2050-205	50 – 1,000	0.1 μF	4.7 μH	0.1 µF
MSW2051-205	400 – 4,000	27 pF	82 nH	270 pF

Evaluation Board Truth Table

RF State	Ant Bias (P1-pin 3)	TX Bias (P1-pin 1)	RX Bias (P1-pin 7)	DC Bias (P1-pin 5)	
Tx-Ant Low Loss	5 V @ 100 mA	0 V @ 100 mA	28 V @ 25 mA	0 V @ 25 mA	
& Tx-Rx Isolation	5 V @ 100 IIIA	0 V @ 100 IIIA	26 V @ 25 IIIA	0 V @ 25 mA	
Ant-Rx Low Loss	5 V @ 100 mA	28 V @ 0 mA	0 V @ 100 mA	28 V @ 0 mA	
& Rx – Tx Isolation	5 V @ 100 IIIA	20 V @ U IIIA	0 V @ 100 IIIA	20 V @ U IIIA	

Minimum Reverse Bias Voltage at TX, RX, DC Ports vs. Signal Frequency

 $P_{_{INC}} = 125 \text{ W CW}, Z_{_0} = 50 \Omega \text{ with } 1.5:1 \text{ VSWR}$

Part Number	F = 50 MHz	F = 100 MHz	F = 200 MHz	F = 400 MHz	F = 1 GHz	F = 4 GHz
MSW2050-205	125 V	125 V	85 V	55 V	28 V	NA
MSW2051-205	NA	NA	125 V	85 V	55 V	28 V

Note: "NA" denotes the switch is not recommended for use in that frequency band.

Absolute Maximum Ratings

 $Z_0 = 50 \Omega$, $T_A = +25$ °C (Unless Otherwise Defined)

Parameter	Conditions	Absolute Maximum Value
Forward Current - Ant, Tx or Rx Port		250 mA
Forward Current - DC Port		150 mA
Reverse Voltage - Tx or Rx Port		125 V
Reverse Voltage - DC Port		125 V
Forward Diode Voltage	$I_{\rm F} = 250 \; \text{mA}$	1.2 V
Operating Temperature		-55°C to 125°C
Storage Temperature		-65°C to 150°C
Junction Temperature		175°C
Assembly Temperature		260°C for 10 s
CW Incident Power Handling – Tx or Ant Port (Note 1)	Source & load VSWR = 1.5 :1, T _{CASE} = 85 °C, cold switching	52 dBm
CW Incident Power Handling – Rx Port (Note 1)	Source & load VSWR = 1.5 :1, $T_{CASE} = 85^{\circ}C$, cold switching	43 dBm
Peak Incident Power Handling – Tx or Ant Port (Note 1)	Source & load VSWR = 1.5 :1, $T_{\text{CASE}} = 85^{\circ}\text{C}$, cold switching, pulse width = 10 μ s, duty cycle = 1 %	58 dBm
Total Dissipated RF & DC Power (Note 1)	$T_{CASE} = 85^{\circ}C$, cold switching	8 W

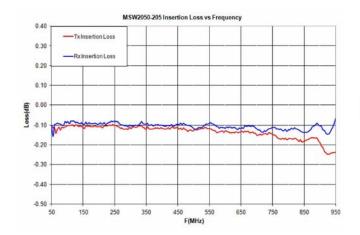
Notes:

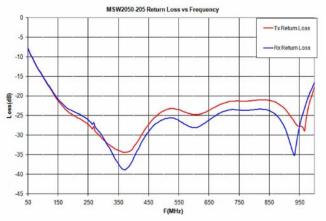
Backside RF and DC grounding area of device must be completely solder-attached to RF circuit board vias for proper electrical and thermal circuit grounding.

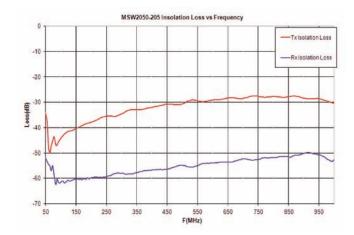


MSW2050-205 Small Signal Typical Performance

 $Z_0 = 50 \Omega$, $T_A = +25^{\circ}C$ (Unless Otherwise Defined)







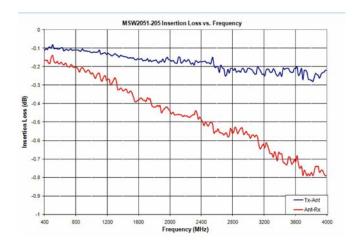
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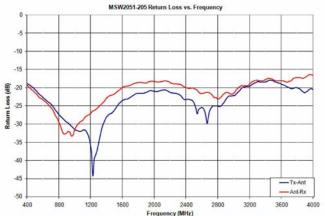


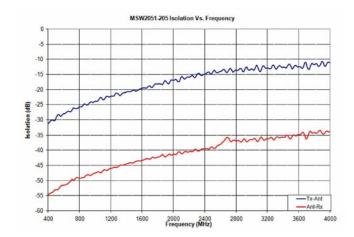


MSW2051-205 Small Signal Typical Performance

 $Z_0 = 50 \Omega$, $T_A = +25^{\circ}C$ (Unless Otherwise Defined)

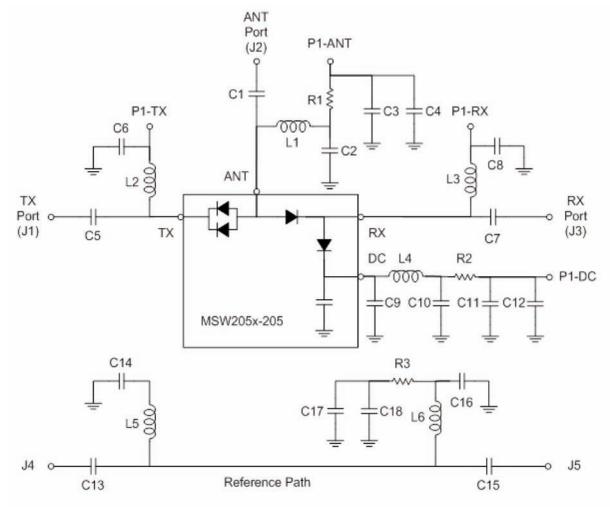








SP2T Switch Evaluation Board Schematic



Evaluation Board Description

The evaluation boards for the MSW2050 family of surface mount silicon PIN diode SP2T T-R switches allow the full exercise of each switch for small signal performance analysis, as well as for large signal operation with maximum input signal power of 45 dBm (CW or peak power). Each evaluation board includes the appropriate MSW205x-205 switch, DC blocking capacitors at each RF port and bias decoupling networks at each RF port which

allow DC or low frequency control signals to be applied to the switch.

Three complementary control signals are required for proper operation. Bias voltages are applied to the TX bias port, RX bias port and the DC bias port to control the state of the switch. A bias voltage of 5 V must be applied to the Ant Bias (pin 3 of multi-pin connector P1) port whenever the switch is in operation.

7



Transmit State

In the TX state, the series PIN diode between the ANT and TX ports is forward biased by applying 0 V to the TX bias input port (pin 1 of multi-pin connector P1). The magnitude of the resultant bias current through the diode is primarily determined by the voltage applied to the ANT bias port (pin 3 of J1), the magnitude of the forward voltage across the PIN diode and the resistance of R1. This current is nominally 100 mA. At the same time, the PIN diode connected between RX and DC ports is also forward biased by applying a higher bias voltage, nominally 28 V, to the RX bias port (pin 7 of P1) and 0 V to the DC bias port (pin 5 of P1). Under this condition, the PIN diode connected between the ANT and RX port is reverse biased and the PIN diode connected between the RX and DC ports is forward biased. The magnitude of the bias current through this diode is primarily determined by the voltage applied to the RX bias port, the magnitude of the forward voltage across the PIN diode and the resistance of R2. This current is nominally 25 mA.

The RX series PIN diode, which is connected between the ANT and RX ports, must be reverse biased during the transmit state. The reverse bias voltage must be sufficiently large to maintain the diode in its non-conducting, high impedance state when large RF signal voltage may be present in the ANT-to-TX path. The reverse voltage across this diode is the arithmetic difference of the bias voltage applied to the RX bias port and the DC forward voltage of the forward-biased transmit series PIN diode.

The minimum voltage required to maintain the series diode on the RX side of the switch out of conduction is a function of the magnitude of the RF voltage present, the standing wave present at the RX series diode's anode, the frequency of the RF signal and the characteristics of the RX series diode, among other factors. Minimum control voltages for several signal frequencies are shown in the table "Minimum Reverse Bias Voltage", assuming the input power to the RX or ANT port to be 100 W CW and the VSWR on the ANT-TX path to be 1.5:1. It is important to note that the evaluation board, as supplied from the factory, is not capable of handling RF input signals larger than 45 dBm. If performance of the switch under larger input signals is to be evaluated, an adequate heat sink must be properly attached to the evaluation board, and several of the passive components on the board must be changed in order to safely handle the dissi-

pated power as well as the high bias voltage necessary for proper performance. Contact the factory for recommended components and heat sink.

Receive State

In the RX state, the series PIN diode between the ANT and RX ports is forward biased by applying 0 V to the RX bias input port (pin 7 of multi-pin connector P1). The magnitude of the resultant bias current through the diode is primarily determined by the voltage applied to the ANT bias port (pin 3 of P1), the magnitude of the forward voltage across the PIN diode and the resistance of R1. This current is nominally 100 mA. At the same time, the PIN diode connected between RX and DC ports is reverse biased by applying a high bias voltage, nominally 28 V, to the DC bias port (pin 5 of P1). A high voltage, nominally 28 V, is also applied to the TX bias port (pin 1 of P1). Under this condition, the PIN diode connected between the ANT and TX port is reverse biased thus isolating the TX RF port from the RX signal path. The reverse voltage across this diode is the arithmetic difference of the bias voltage applied to the TX bias port and the DC forward voltage of the forward-biased receive series PIN diode. The minimum voltage required to maintain the series diode on the TX side of the switch out of conduction is a function of the magnitude of the RF voltage present, the standing wave present at the RX series diode's anode, the frequency of the RF signal and the characteristics of the TX series diode, among other factors. For typical receive-level signals, this diode is held out of conduction with a relatively small reverse bias voltage.

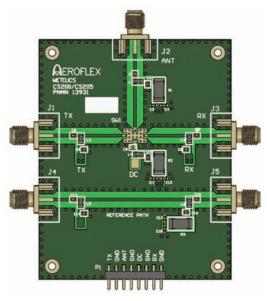
The values of the reactive components which comprise the bias decoupling networks as well as the signal path DC blocking are shown in the table RF Bias Network Component Values.

Reference Path

A reference path is provided on the evaluation board, complete with bias decoupling networks, so that the magnitude of the insertion loss of the micro strip transmission lines connected to the switch and the associated bias decoupling components can be measured and removed from the measured performance of the switch.



SP2T Switch Evaluation Board Layout



Assembly Instructions

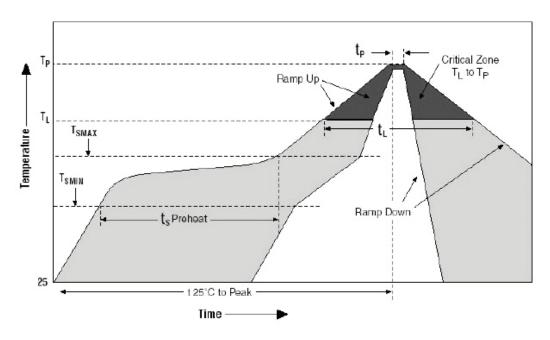
The MSW2050-205 and MSW2051-205, switches are capable of being placed onto circuit boards with pick and place manufacturing equipment from tube or tape-reel dispensing. The devices are attached to the circuit board using conventional solder re-flow or wave soldering procedures with RoHS type or Sn60/Pb40-type solders per Table I and Figure I



Table 1. Time-Temperature Profile for Sn60/Pb40 or RoHS Type Solders

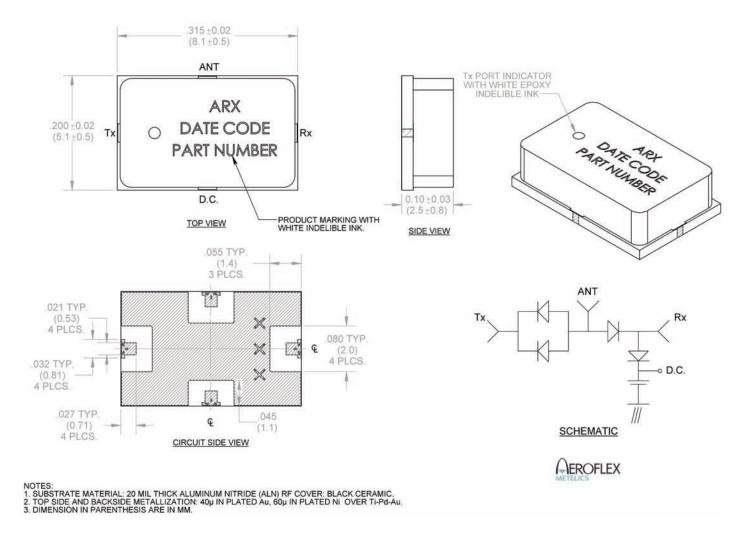
Profile Feature	SnPb Solder Assembly	Pb-Free Solder Assembly
Average Ramp-Up Rate (T _L to T _P)	3°C /second maximum	3°C /second maximum
Preheat:		
- Temperature Min (T _{SMIN})	100°C	150°C
- Temperature Max (T _{smax})	1 <mark>50</mark> ℃	200°C
- Time (min to max)(t _s)	60-120 s	60-180 s
T _{SMAX} to T _L - Ramp-Up Rate		3°C/s maximum
Time Maintained Above: - Temperature (T _L) - Time (t _L)	183°C 60-150 s	217°C 60-150 s
Peak temperature (T _P)	225 +0/-5°C	260 +0/-5°C
Time Within 5°C of Actual Peak Temperature (t _p)	10 – 30 s	20 – 40 s
Ramp-Down Rate	6°C /s maximum	6°C /s maximum
Time 25°C to Peak Temperature	6 minutes maximum	8 minutes maximum

Figure 1. Solder Re-Flow Time-Temperature Profile





MSW2050-205 and MSW2051-205 SP2T Switch Outline (CS205)

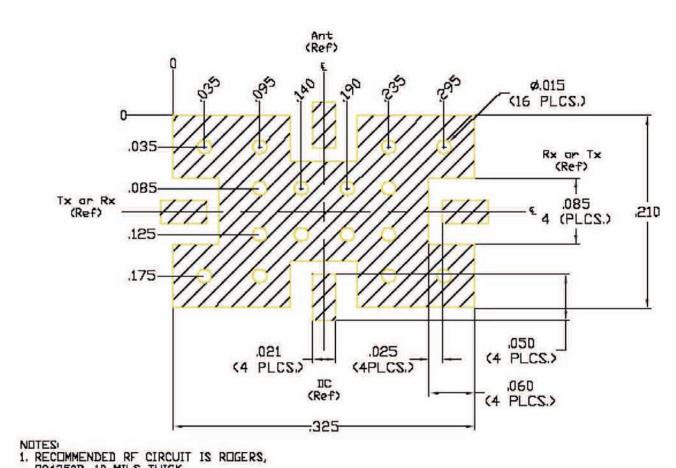


Notes:

1. Hatched Metal Area on Circuit Side of Device is RF and D.C. Ground.



RF Circuit Solder Footprint for Case Style 205 (CS205)



RO4350B, 10 MILS THICK.

Hatched area is RF, DC, and thermal Ground. Vias should be solid copper fill and gold plated for optimum heat transfer from backside of switch module through Circuit Vias to metal thermal ground.

12



Part Number Ordering Information

Part Number	Description	Packaging
MSW2050-205-T		Tube
MSW2050-205-R		Tape-Reel (Quantities of 250 or 500)
MSW2050-205-W		Waffle Pack
MSW2051-205-T	Tube	
MSW2051-205-R	Tape-Reel (Quantities of 250	
MSW2051-205-W		Waffle Pack
MSW2050-205-E		RF Evaluation Board
MSW2051-205-E		RF Evaluation Board

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